

## Electronic Supplementary Information

### Electrostatic Self-Assembly of AgI/Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub> p-n Junction Photocatalyst for Boosting Superoxide Radical Generation

Jin Liu,<sup>a</sup> Xingcai Zhang,<sup>b</sup> Qian Zhong,<sup>a</sup> Jun Li,<sup>\*c</sup> Hongzhang Wu,<sup>a</sup> Bo Zhang,<sup>a</sup> Lin

Jin,<sup>\*a</sup> Hua Bing Tao,<sup>\*d</sup> and Bin Liu<sup>\*d</sup>

<sup>a</sup> Henan Key Laboratory of Rare Earth Functional Materials, International Joint Research Laboratory for Biomedical Nanomaterials of Henan, Zhoukou Normal University, Zhoukou 466001, P. R. China

<sup>b</sup> John A. Paulson School of Engineering and Applied Sciences, Harvard University, Cambridge, MA, 02138, United States

<sup>c</sup> Henan Institute of Advanced Technology, Zhengzhou University, Zhengzhou 450001, P. R. China

<sup>d</sup> School of Chemical and Biomedical Engineering, Nanyang Technological University, 62 Nanyang Drive, Singapore 637459, Singapore

\*Corresponding author, E-mail address: junlee1992@126.com (Jun Li), jinlin\_1982@126.com (Lin Jin), hbtao@ntu.edu.sg (Hua Bing Tao), liubin@ntu.edu.sg (Bin Liu)

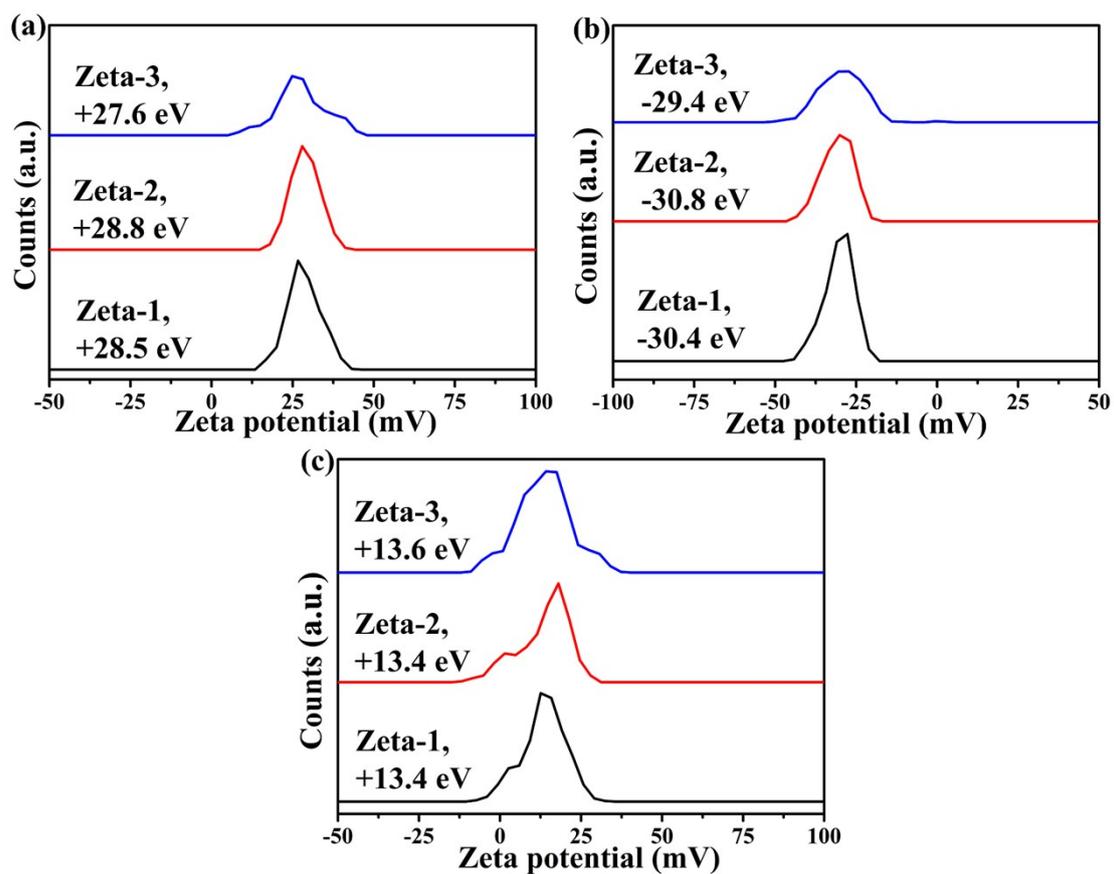


Fig. S1 Zeta potential of (a)  $\text{Bi}_2\text{Ga}_4\text{O}_9$ , (b) AgI and (c) 25%-AgI/  $\text{Bi}_2\text{Ga}_4\text{O}_9$ . Zeta-1, Zeta-2, and Zeta-3 represent the first, second and third time measurement results, respectively.

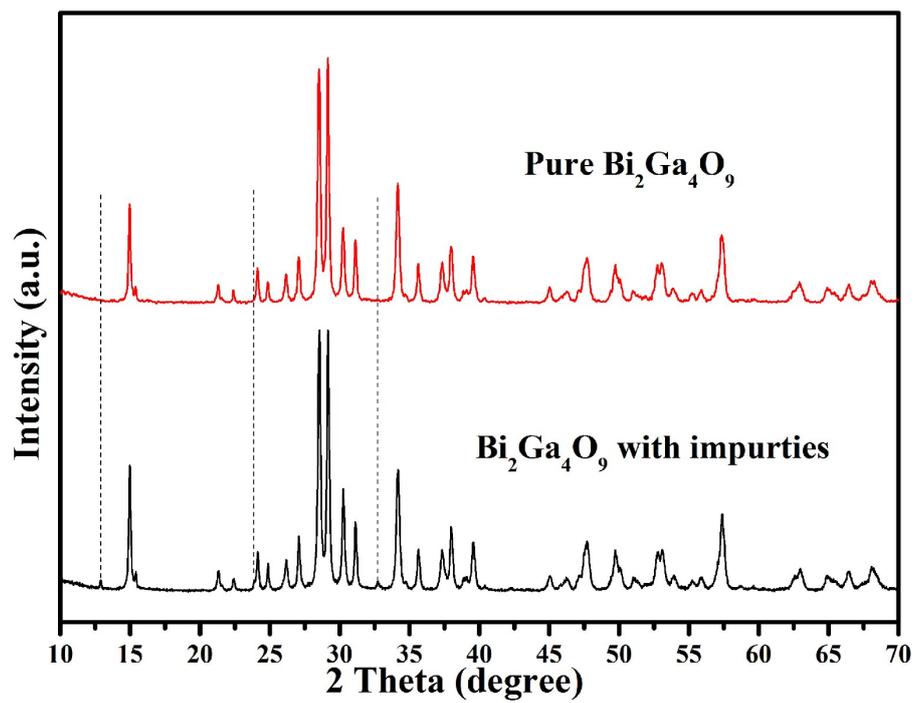


Fig. S2 XRD patterns of  $\text{Bi}_2\text{Ga}_4\text{O}_9$  with impurities and pure  $\text{Bi}_2\text{Ga}_4\text{O}_9$ .

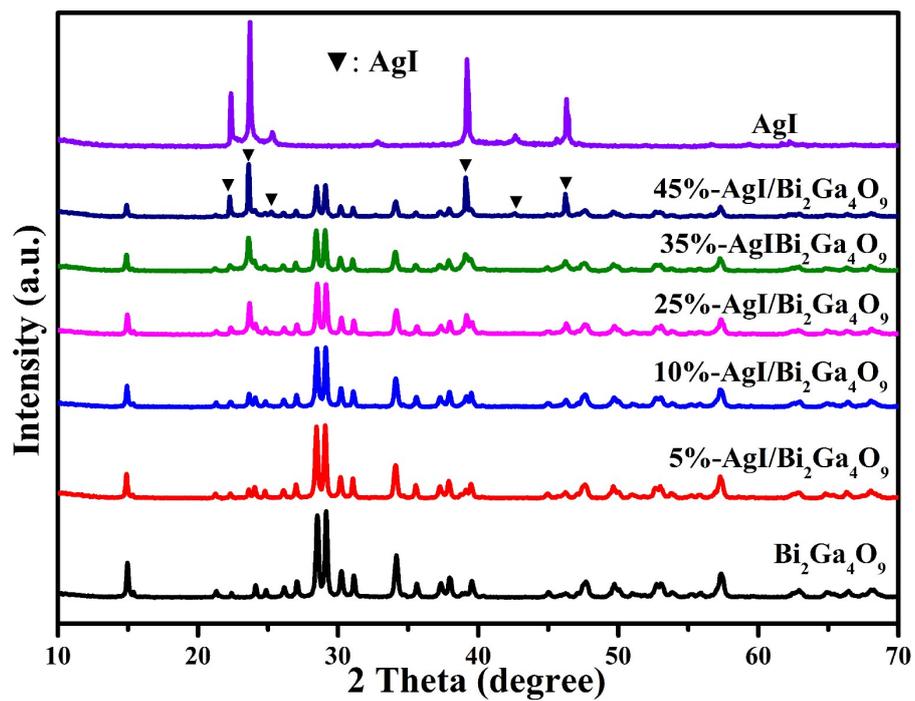


Fig. S3 XRD patterns of Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub>, AgI and AgI/Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub> samples.

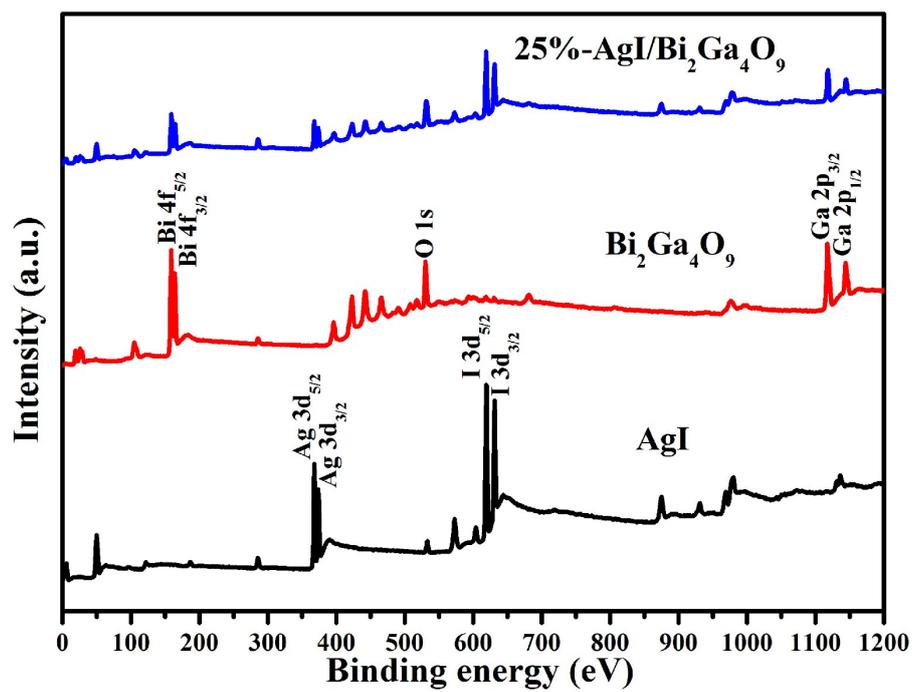


Fig. S4 XPS survey spectra.

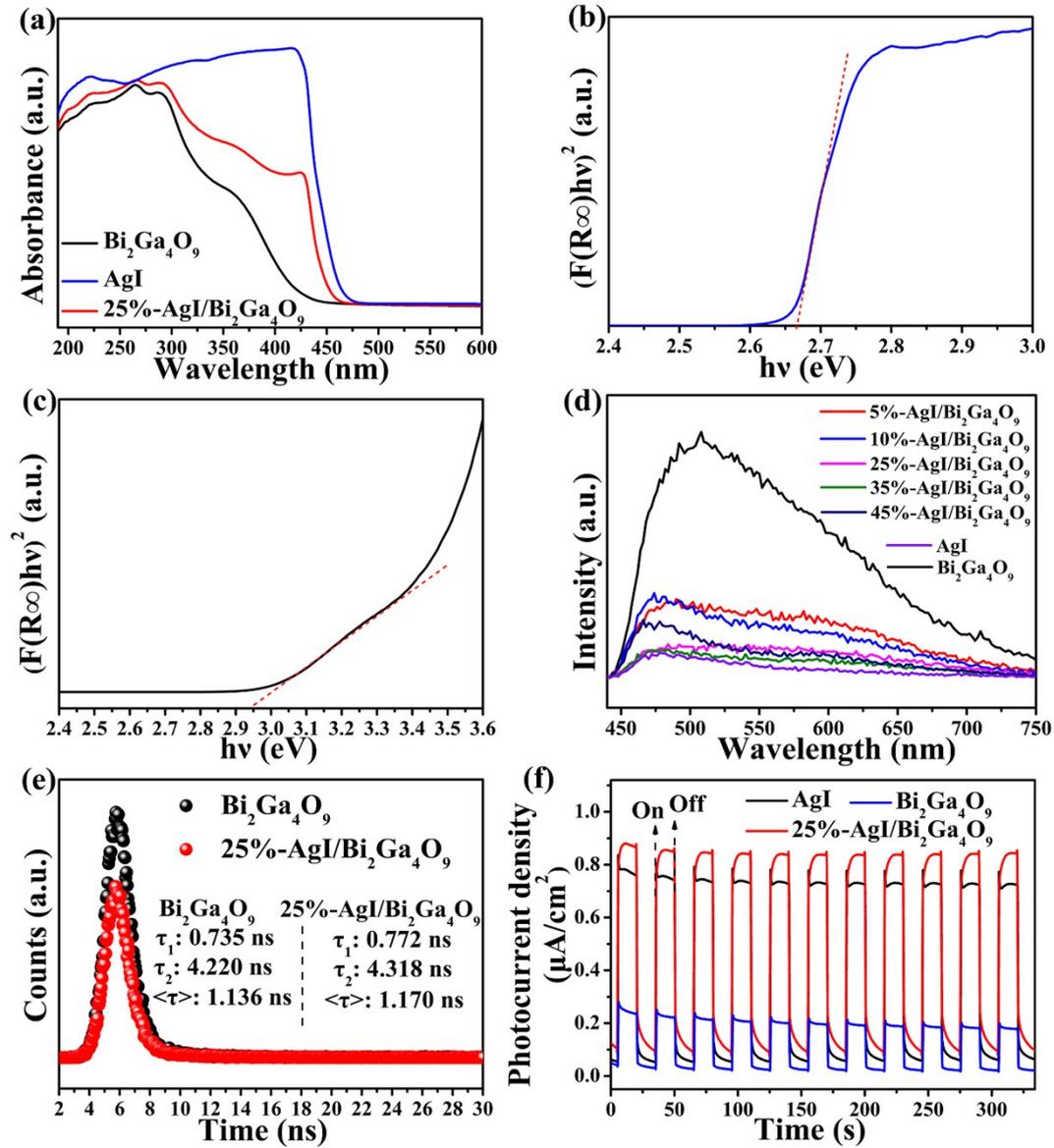


Fig. S5 (a) UV-vis absorption spectra. (b) Plot of  $(F(R_\infty)hv)^2$  vs. photon energy for AgI. (c) Plot of  $(F(R_\infty))^{1/2}$  vs. photon energy for Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub>. (d) PL spectra, (e) time-resolved PL decay curves, and (f) change of photocurrent density with time.

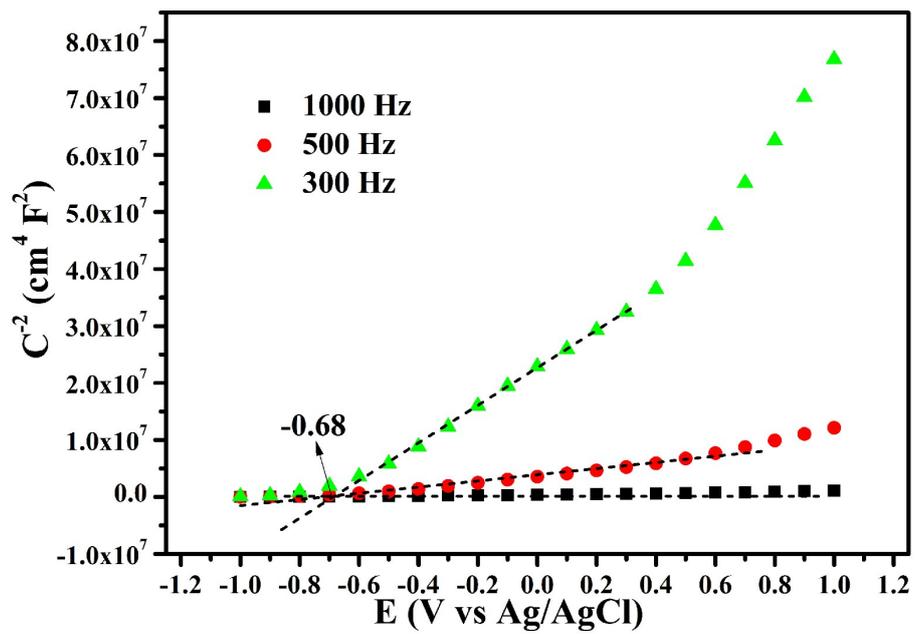


Fig. S6 Mott-Schottky plots of  $\text{Bi}_2\text{Ga}_4\text{O}_9$ .

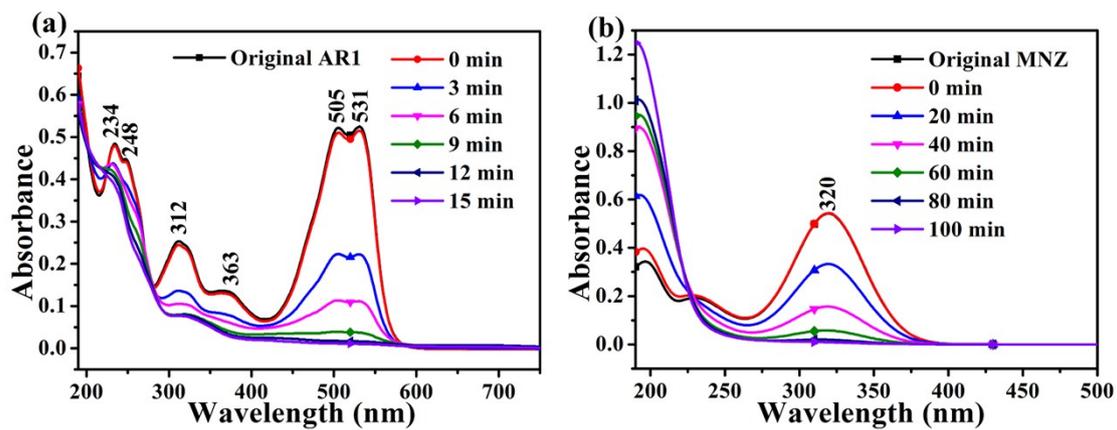
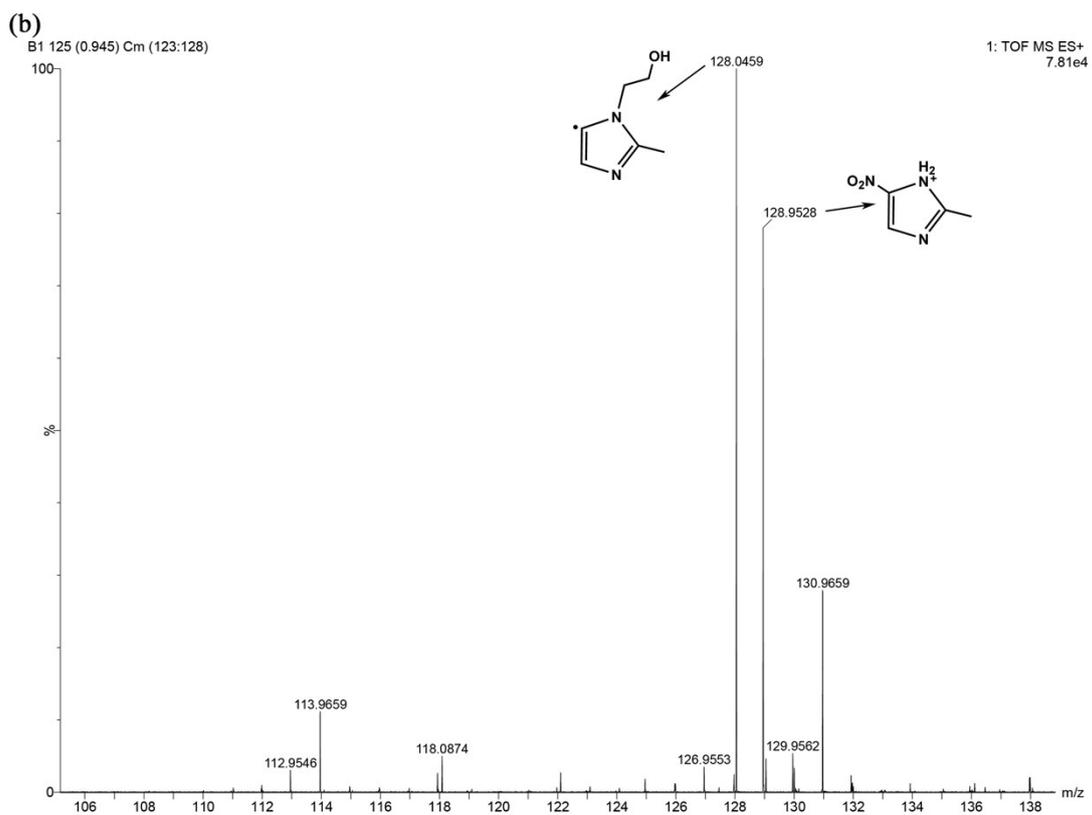
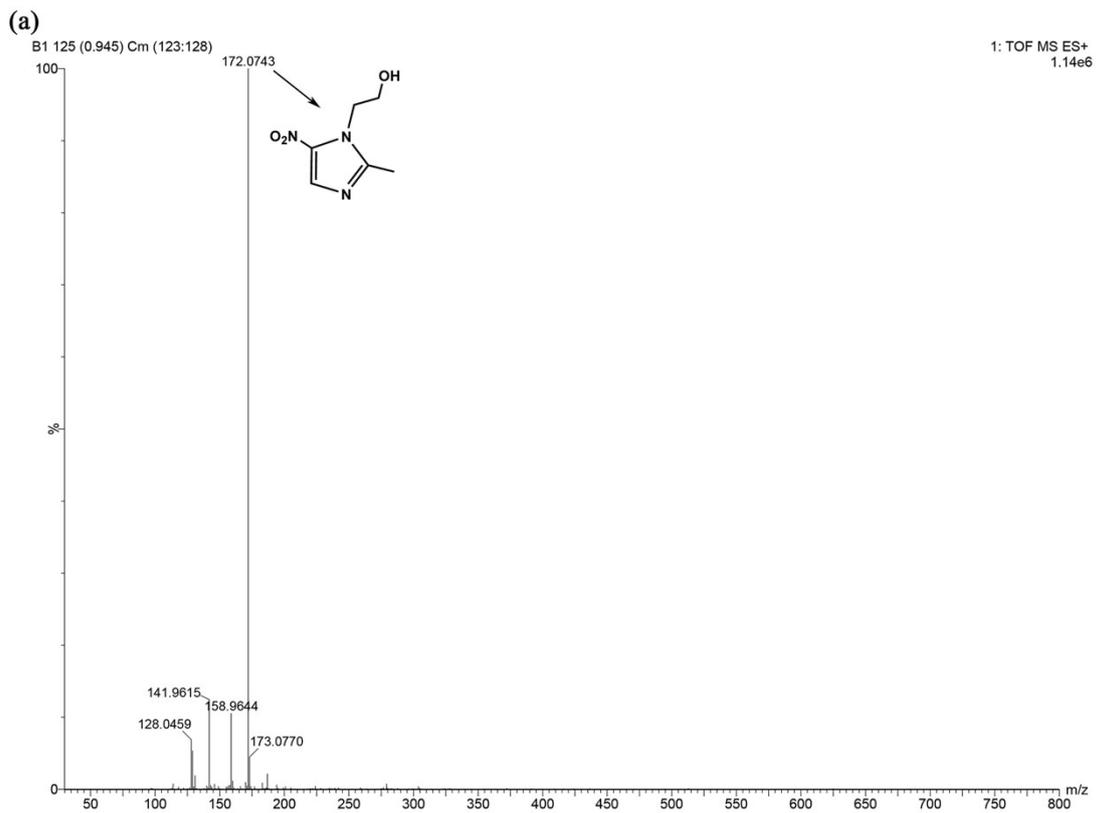


Fig. S7 UV-vis absorption spectra of (a) AR1 and (b) MNZ recorded after different durations of irradiation over 25%-AgI/Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub>.



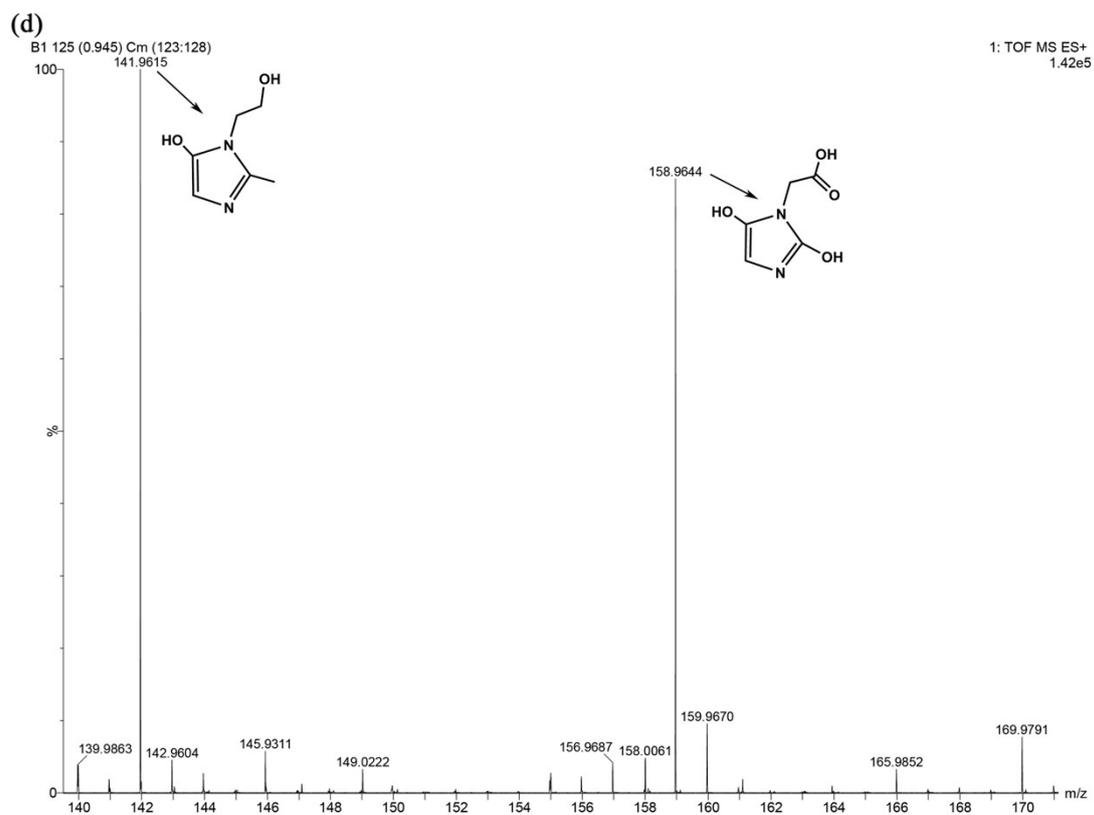
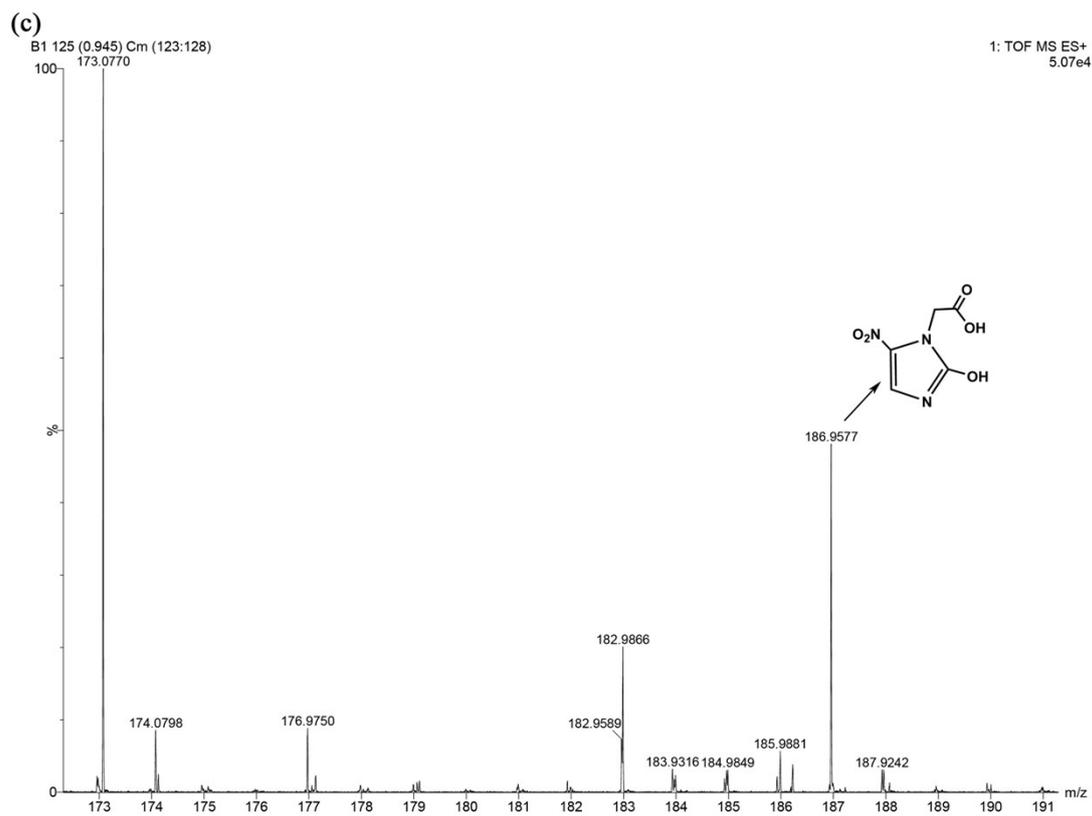


Fig. S8 Mass spectra and molecular structures of the intermediates in the photocatalytic degradation of MNZ over 25%-AgI/Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub>.

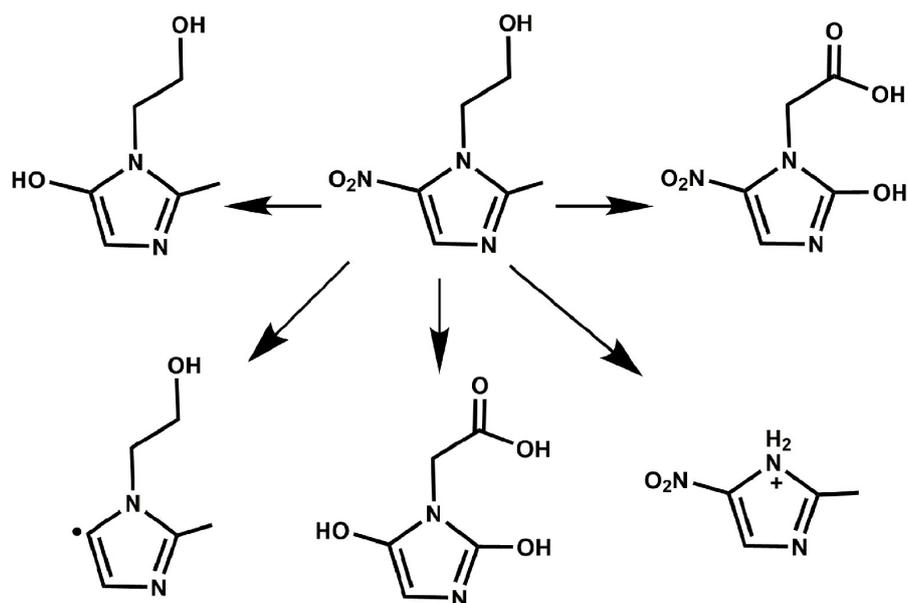


Fig. S9 Possible photocatalytic degradation pathways of MNZ.

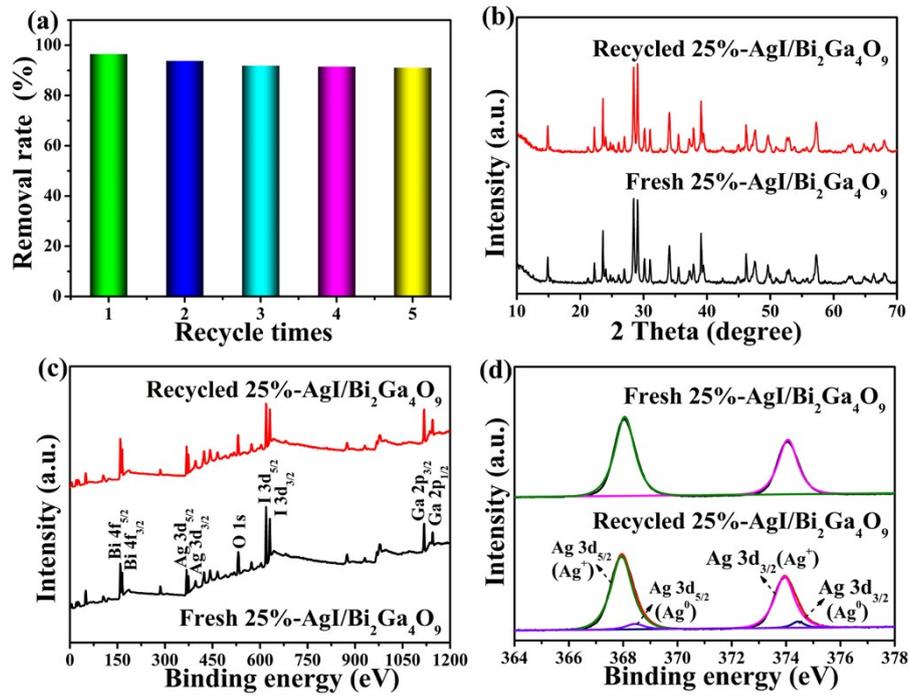


Fig. S10 (a) Recycling runs of 25%-AgI/Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub> for the photocatalytic degradation of AR1. (b) XRD patterns and (c) XPS survey spectra and (d) high resolution XPS Ag 3d spectra of the fresh and recycled 25%-AgI/Bi<sub>2</sub>Ga<sub>4</sub>O<sub>9</sub>.

Table S1 The electrical properties of AgI sample.

Sample	Hall mobility ( $\text{m}^2/\text{V}\cdot\text{s}$ )	Carrier concentration ( $1/\text{m}^3$ )	Hall coefficient ( $\text{m}^3/\text{C}$ )	Resistivity ( $\Omega\cdot\text{m}$ )	Hall voltage (V)	Conduction type
AgI	$1.613\times 10^{-2}$	$1.919\times 10^{19}$	0.325	20.165	$2.681\times 10^{-3}$	p